

## SANYO Semiconductors DATA SHEET



## **Thick-Film Hybrid IC** STK433-060-E - 2-channel class AB audio power IC, 50W+50W

#### **Overview**

The STK433-060-E is a hybrid IC designed to be used in 50W × 2ch class AB audio power amplifiers.

#### Applications

· Audio power amplifiers.

#### Features

- Pin-to-pin compatible outputs ranging from 30W to 60W.
- Can be used to replace the STK433-100 series (80W to 150W/2ch)and STK433-200/-300 series (3-channel) due to its pin compatibility
- Miniature package (47.0mm × 25.6mm × 9.0mm)
- Output load impedance:  $R_{\rm L} = 6\Omega$  to  $4\Omega$  supported
- Allowable load shorted time: 0.3 second
- Allows the use of predesigned applications for standby and mute circuits.

#### Series Models

	STK433-030-E	STK433-040-E	STK433-060-E	STK433-070-E				
Output 1 (10%/1kHz)	30W×2 channels	40W×2 channels	50W×2 channels	60W×2 channels				
Output 2 (0.4%/20Hz to 20kHz)	20W×2 channels	25W×2 channels	35W×2 channels	40W×2 channels				
Max. rated V <sub>CC</sub> (quiescent)	±34V	±38V	±46V	±50V				
Max. rated V <sub>CC</sub> (6 $\Omega$ )	±32V	±36V	±40V	±44V				
Max. rated V <sub>CC</sub> (4 $\Omega$ )	±26V	±30V	±33V	±37V				
Recommended operating $V_{CC}$ (6 $\Omega$ )	±21V	±24V	±27V	±29V				
Dimensions (excluding pin height)	47.0mm×25.6mm×9.0mm							

- Any and all SANYO Semiconductor Co., Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

SANYO Semiconductor Co., Ltd. www.semiconductor-sanyo.com/network

## **Specifications**

Absolute Maximum Ratings at Ta = 25°C (excluding rated temperature items), Tc=25°C unless otherwise specified

Parameter	Symbol	Conditions	Ratings	Unit
Maximum quiescent supply voltage 0	V <sub>CC</sub> max (0)	When no signal	±46	V
Maximum supply voltage 1	V <sub>CC</sub> max (1)	$R_{L} \ge 6\Omega$	±40	V
Maximum supply voltage 2	V <sub>CC</sub> max (2)	$R_L=4\Omega$	±33	V
Minimum operating supply voltage	V <sub>CC</sub> min		±10	V
Pin 13 input voltage	VST max		-0.3 to +5.5	V
Thermal resistance	өј-с	Per power transistor	3.5	°C/W
Junction temperature	Tj max	Both the Tj max and Tc max conditions must be met.	150	°C
IC substrate operating temperature Tc max			125	°C
Storage temperature	Tstg		-30 to +125	°C
Allowable load shorted time *4	ts	V <sub>CC</sub> =±27V, R <sub>L</sub> =6Ω, f=50Hz, P <sub>O</sub> =35W, 1-channel active	0.3	s

### $\label{eq:constraint} \textbf{Operating Characteristics} \ at \ Tc=25^{\circ}C, \ R_{L}=6\Omega, \ R_{g}=600\Omega, \ VG=30dB, \ non-inductive \ load \ R_{L}, \ unless \ otherwise$

specified										
			(	Condition	is *2					
Parameter	Symbol	V <sub>CC</sub> (V)	f (Hz)	P <sub>O</sub> (W)	THD (%)		min	typ	max	unit
Output power *1	P <sub>O</sub> (1)	±27	20 to 20k		0.4		33	35		
	P <sub>O</sub> (2)	±27	1k		10			50		W
	P <sub>O</sub> (3)	±22	1k		1	$R_L=4\Omega$		35		
Total harmonic distortion *1	THD (1)	±27	20 to 20k	5.0					0.4	%
	THD (2)	±27	1k	5.0				0.02		%
Frequency characteristics *1	fL, fH	±27		1.0		+0 -3dB		20 to 50k		Hz
Input impedance	ri	±27	1k	1.0				55		kΩ
Output noise voltage *3	V <sub>NO</sub>	±33				Rg=2.2kΩ			1.0	mVrms
Quiescent current	ICCO	±33				No loading	20	45	70	mA
Standby current	ICST	±33							1	mA
Output neutral voltage	V <sub>N</sub>	±33					-70	0	+70	mV
Pin 13 voltage when standby ON	VST ON	±27				Standby			0.6	V
Pin 13 voltage when standby OFF	VST OFF	±27				Operating	2.5			V

[Remarks]

\*1: For 1-channel operation

\*2: Unless otherwise specified, use a constant-voltage power supply to supply power when inspections are carried out.

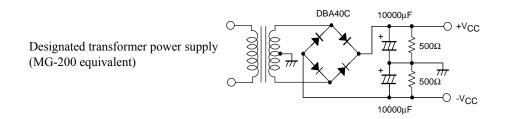
\*3: The output noise voltage values shown are peak values read with a VTVM. However, an AC stabilized (50Hz) power supply should be used to minimize the influence of AC primary side flicker noise on the reading.

\*4: Use the transformer power supply circuit shown in the figure below for allowable load shorted time measurement.

\*5: Please connect -preV<sub>CC</sub> Pin (#1 pin) with the stable minimum voltage and connect so that current does not flow in by reverse bias.

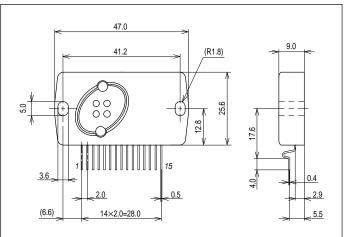
\* Thermal design must be implemented based on the conditions under which the customer's end products are expected to operate on the market.

\* A thermoplastic adhesive is used to adhere the case.

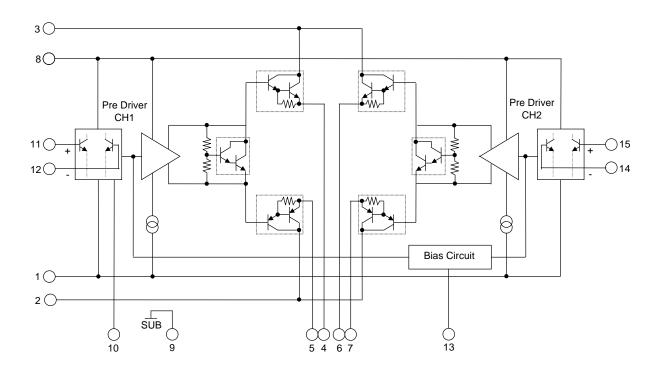


## Package Dimensions

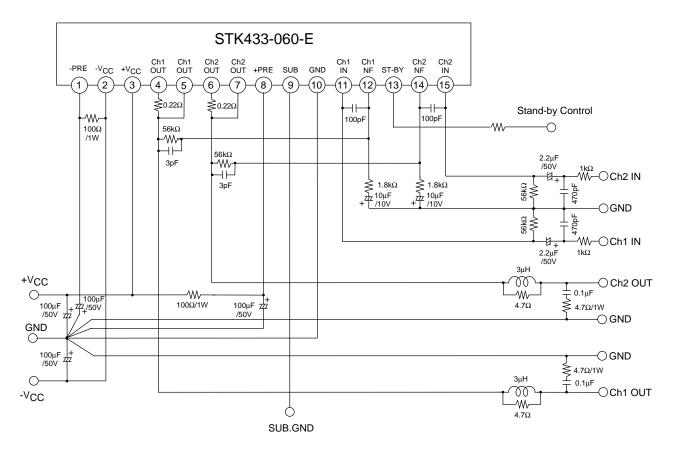
unit:mm (typ)



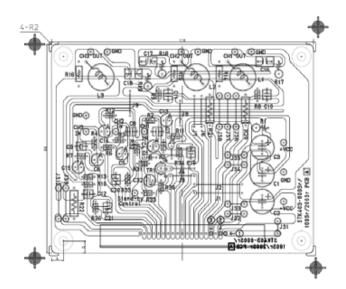
## Internal Equivalent Circuit



## Application Circuit Example



Sample PCB Trace Pattern



## STK433-000/-200/STK403-100Sr PCB PARTS LIST

PCB Name: STK403-000Sr/100Sr/200Sr PCBA

				Component					
Lessier Ne. (*	2)	DADTO	DATINO	STK433-030/-040	STK433-060/-070				
Location No. (*	3)	PARTS	RATING	STK433-230/-240	STK433-260/-270				
					STK403-090 to130				
Hybrid IC#1 Pin Position		-	-	- D					
R01		ERG1SJ101	100Ω, 1W	ena	able				
R02, R03 (R4)		RN16S102FK	1kΩ, 1/6W	ena	able				
R05, R06, R08, R09 (R7, I	R10)	RN16S563FK	56kΩ, 1/6W	ena	able				
R11, R12 (R13)		RN16S182FK	1.8kΩ, 1/6W	ena	able				
R14, R15 (R16)		RN14S4R7FK	4.7Ω, 1/4W	ena	able				
R17, R18 (R19)		ERX1SJ4R7	4.7Ω, 1W	ena	able				
R20, R21 (R22)		ERX2SJR22	0.22Ω, 2W	short	enable				
C01, C02, C03		100MV100HC	100μF, 100V	ena	able				
C04, C05 (C06)		50MV2R2HC	2.2μF, 50V	enab	le (*1)				
C07, C08 (C09)		DD104-63B471K50	470pF, 50V	ena	able				
C10, C11 (C12)		DD104-63CJ030C50	3pF, 50V	enab	le (*2)				
C13, C14 (C15)		10MV10HC	10μF, 10V	enab	le (*1)				
C16, C17 (C18)		ECQ-V1H104JZ	0.1µF, 50V	ena	able				
C19, C20 (C21)		DD104-63B***K50	***pF, 50V	100	0pF				
R34, R35 (R36)		RN16S302FK	3kΩ, 1/6W	Sh	ort				
L01, L02 (L3)		-	ЗμН	ena	able				
Stand-By Control Circuit	Tr1	2SC2274 (Reference)	VCE≥50V, IC≥10mA	ena	enable				
	D1	GMB01 (Reference)	Di	ena	able				
	R30	RN16S512FK	5.1kΩ, 1/6W	STK433-*00series					
		RN16S103FK	13kΩ, 1/6W	13kΩ, 1/6W STK403-					
	R31	RN16S333FK	33kΩ, 1/6W	ena	able				
	R32	RN16S102FK	1kΩ, 1/6W	ena	able				
	R33	RN16S202FK	2kΩ, 1/6W	ena	able				
	C32	10MV33HC	33μF, 10V	ena	enable				
J1, J2, J3, J4, J5, J6, J8, J	19	-	-	ena	able				
J7, JS2, JS3, JS4, JS5, JS	87 JS8, JS9	-	-		-				
JS6, JS10		-	-	ena	enable				
JS1		-	-	ena	able				

(\*1) Capacitor mark "A" side is "-" (negative).

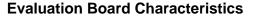
(\*2) STK433-200Sr (3ch) is 8pF use.

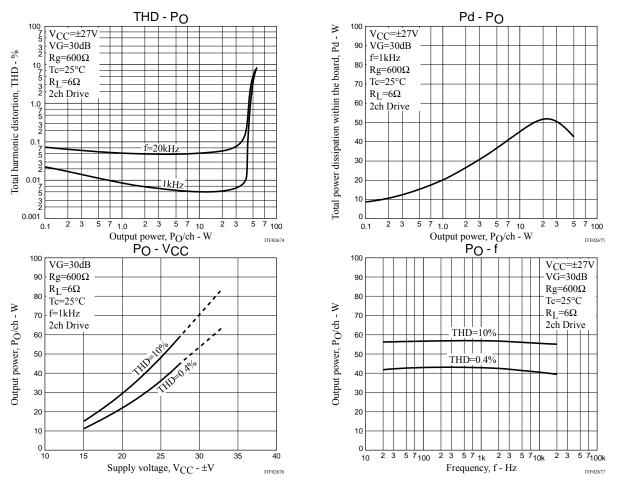
(\*3) Location No.() parts is STK433-200Sr (3ch) only use.

## **Pin Assignments**

[STK433-000/-100/-200Sr & STK415/416-100Sr Pin Layout]

[S1K433-000/-100/-200Sr 8	corr	141	5/41	10-1	005	эг г.	шL	ayu	uu														
					1	2	3	4	5	6	7	8	9	10	11	12	13	14	15				
2-channel class-AB		2-channel class AB/2.00mm																					
STK433-030-E 30W/JEITA					-	-	+	0	0	0	0	+			Ι	Ν	S	Ν	Ι				
STK433-040-E 40W/JEITA					Р	v	v	U	U	U	U	Р	s	G	Ν	F	т	F	Ν				
STK433-060-E 50W/JEITA					R	С	С	т	т	т	т	R	U	Ν	/	/	А	/	/				
STK433-070-E 60W/JEITA					Е	с	с	1	1	/	7	Е	в	D	С	с	Ν	С	с				
							-	С	С	С	С				Н	н	D	н	н				
STK433-090-E 80W/JEITA								н	Н	н	н		G		1	1		2	2				
STK433-100-E 100W/JEITA								1	1	2	2		N				В						
STK433-120-E 120W/JEITA								+	-	+	-		D				Y						
STK433-130-E 150W/JEITA													-										
					1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19
3-channel class-AB						2	5	4	-			-	B/2			12	15	14	15	10	17	10	13
	_							6	-	1			AD/2		u11		-					6	
STK433-230A-E 30W/JEITA					-	-	+	0	0	0	0	+				Ν	S	N	1		N	0	0
STK433-240A-E 40W/JEITA					Ρ	V	V	U	U	U	U	Ρ	S	G	Ν	F	т	F	Ν	Ν	F	U	U
STK433-260A-E 50W/JEITA					R	С	С	Т	Т	Т	Т	R	U	Ν	/	/	А	/	/	/	/	Т	т
STK433-270-E 60W/JEITA					Е	С	С	/	/	/	/	Е	В	D	С	С	Ν	С	С	С	С	/	/
STK433-290-E 80W/JEITA								С	С	С	С		•		н	н	D	н	н	н	Н	С	С
STK433-300-E 100W/JEITA								н	н	н	н		G		1	1		2	2	3	3	Н	н
STK433-320-E 120W/JEITA								1	1	2	2		Ν				В					3	3
STK433-330-E 150W/JEITA		r	1	r				+	-	+	-		D				Y					+	-
2-channel class-H	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19				
									2	char	nnel	class	H/2.	00m	m								
STK415-090-E 80W/JEITA	+	-	+	-	-	-	+	0	0	0	0	+			1	Ν	S	Ν	Ι				
STK415-100-E 90W/JEITA	V	V	0	0	Р	V	V	U	U	U	U	Р	s	G	Ν	F	т	F	Ν				
STK415-120-E 120W/JEITA	L	L	F	F	R	н	н	т	т	Т	т	R	U	Ν	/	/	А	/	/				
STK415-130-E 150W/JEITA			F	F	Е			7	/	/	/	Е	в	D	С	С	Ν	С	С				
STK415-140-E 180W/JEITA			s	s				С	С	С	С		•		н	н	D	н	н				
			Е	Е				н	н	н	н		G		1	1		2	2				
			т	т				1	1	2	2		Ν				В						
								+	-	+	-		D				Υ						
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23
3-channel class-H									3.	char	nnel	class	H/2.	00m	m								
STK416-090-E 80W/JEITA	+	-	+	-	-	-	+	0	0	0	0	+			Ι	Ν	s	Ν	Ι	Ι	Ν	0	0
STK416-100-E 90W/JEITA	v	v	0	ο	Р	v	v	U	U	U	U	P	s	G	N	F	т	F	N	N	F	U	U
STK416-120-E 120W/JEITA	Ĺ	L	F	F	R	н	н	Т	Т	Т	Т	R	U	N	/		A		/	/		Т	Т
STK416-130-E 150W/JEITA	-	-	F	F	E			,	,	,	,	E	в	D	ċ	c	N	c	ć	ċ	ć	,	,
2			s	s	-			ċ	c	ć	ċ	-	•		н	н	D	н	н	н	н	ć	c
			E	E				н	н	н	н		G		1	1		2	2	3	3	н	н
			Т	Т				1	1	2	2		N			'	В	-	-	Ŭ	U	3	3
			<sup>•</sup>	·				+		+	-		D				Y					+	Ĭ
						1																L '	





[Thermal Design Example for STK433-060-E ( $R_L = 6\Omega$ )]

The thermal resistance,  $\theta$ c-a, of the heat sink for total power dissipation, Pd, within the hybrid IC is determined as follows.

Condition 1: The hybrid IC substrate temperature, Tc, must not exceed 125°C.

 $Pd \times \theta c - a + Ta < 125^{\circ}C$  (1)

Ta: Guaranteed ambient temperature for the end product

Condition 2: The junction temperature, Tj, of each power transistor must not exceed 150°C.

 $Pd \times \theta c\text{-}a + Pd/N \times \theta j\text{-}c + Ta < 150^{\circ}C$ 

N: Number of power transistors

 $\theta$ j-c: Thermal resistance per power transistor

However, the power dissipation, Pd, for the power transistors shall be allocated equally among the number of power transistors.

The following inequalities result from solving equations (1) and (2) for  $\theta$ c-a.

 $\theta c-a < (125 - Ta)/Pd$  .....(1)'  $\theta c-a < (150 - Ta)/Pd - \theta j-c/N$  .....(2)'

(2)

Values that satisfy these two inequalities at the same time represent the required heat sink thermal resistance. When the following specifications have been stipulated, the required heat sink thermal resistance can be determined from formulas (1)' and (2)'.

<ul> <li>Supply voltage</li> </ul>	VCC
Load resistance	Rī

•	Loau resistance	кL
-	Guaranteed ambient temperature	Та

• Guaranteed ambient temperature Ta

#### [Example]

When the IC supply voltage,  $V_{CC}$ , is  $\pm 27V$  and  $R_L$  is  $6\Omega$ , the total power dissipation, Pd, within the hybrid IC, will be a maximum of 52W at 1kHz for a continuous sine wave signal according to the Pd-P<sub>O</sub> characteristics. For the music signals normally handled by audio amplifiers, a value of 1/8P<sub>O</sub> max is generally used for Pd as an estimate of the power dissipation based on the type of continuous signal. (Note that the factor used may differ depending on the safety standard used.)

This is:

 $Pd \approx 40W$  (when 1/8P<sub>O</sub> max. = 6.25W, P<sub>O</sub> max. = 50W).

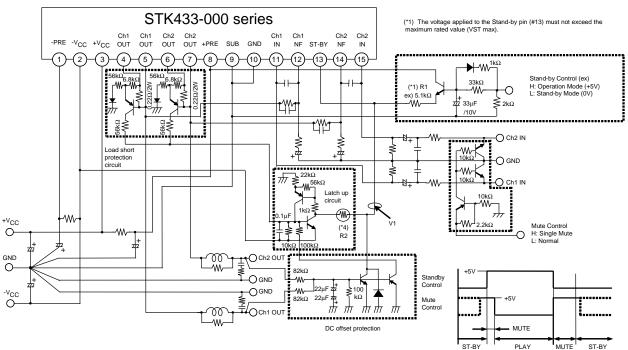
The number of power transistors in audio amplifier block of these hybrid ICs, N, is 4, and the thermal resistance per transistor,  $\theta$ j-c, is 3.5°C/W. Therefore, the required heat sink thermal resistance for a guranteed ambient temperature, Ta, of 50°C will be as follows.

From formula (1)'	$\theta$ c-a < (125 - 50)/40
	< 1.87
From formula (2)'	$\theta$ c-a < (150 - 50)/40 - 3.5/4
	< 1.62

Therefore, the value of 1.62°C/W, which satisfies both of these formulae, is the required thermal resistance of the heat sink.

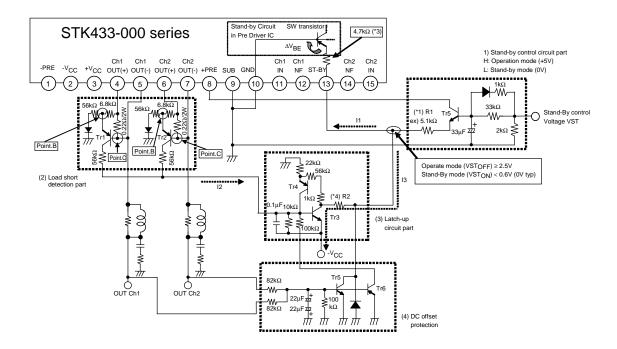
Note that this thermal design example assumes the use of a constant-voltage power supply, and is therefore not a verified design for any particular user's end product.

# STK433-000 Series Standby Control, Mute Control, Load-short Protection & DC offset Protection application



(\*1) R1 is changed depending on the power-supply voltage (-VCC). Please set resistance (R1) to become "V1 = 0V" by the following calculation types.

#### STK433-000 Series Application Explanation



The protection circuit application for the STK433-000sr consists of the following blocks (blocks (1) to (4)).

- (1) Standby control circuit block
- (2) Load short-circuit detection block
- (3) Latch-up circuit block
- (4) DC voltage protection block
- 1) Standby control circuit block

Concerning pin 13 reference voltage VST

<1> Operation mode

The switching transistor of the predriver IC turns on when the pin 13 reference voltage, VST, becomes greater than or equal to 2.5V, placing the amplifier into the operation mode.

Example: When VST (min.) = 2.5V

I1 is approximately equal to 0.40mA since VST =  $(*2) \times IST + 0.6V \rightarrow 2.5V = 4.7k\Omega \times IST + 0.6V$ .

<2> Standby mode

The switching transistor of the predriver IC turns off when the pin 13 reference voltage, VST, becomes lower than or equal to 0.6V (typ. 0V), placing the amplifier into the standby mode. Example: When VST = 0.6V

It is approximately equal to 0mA since VST = (\*2) × IST + 0.6V  $\rightarrow$  0.6V = 4.7k $\Omega$  × IST + 0.6V.

(\*1) Limiting resistor

Determine the value of R1 so that the voltage VST applied to the standby pin (pin 13) falls within the rating (+2.5V to 5.5V (typ. 3.0V)).

- (\*2) The standby control voltage must be supplied from the host including microcontrollers.
- (\*3) A 4.7k $\Omega$  limiting resistor is also incorporated inside the hybrid IC (at pin 13).

#### 2) Load short-circuit detection block

Since the voltage between point B and point C is less than 0.6V in normal operation mode ( $V_{BE} < 0.6V$ ) and TR1 (or TR2) is not activated, the load short-circuit detection block does not operate.

When a load short-circuit occurs, however, the voltage between point B and point C becomes larger than 0.6V, causing TR1 (or TR2) to turn on ( $V_{BE} > 0.6V$ ), and current I2 to flows.

3) Latch-up circuit block

TR3 is activated when I2 is supplied to the latch-up circuit.

When TR3 turns on and current I3 starts flowing, VST goes down to 0V (standby mode), protecting the power amplifier.

Since TR3 and TR4 configure a thyristor, once TR3 is activated, the IC is held in the standby mode.

To release the standby mode and reactivate the power amplifier, it is necessary to set the standby control voltage (\*2) temporarily low (0V). Subsequently, when the standby control is returned to high, the power amplifier will become active again.

(\*4) The I3 value varies depending on the supply voltage. Determine the value of R2 using the formula below, so that I1 is equal to or less than I3.

 $I1 \le I3 = V_{CC}/R2$ 

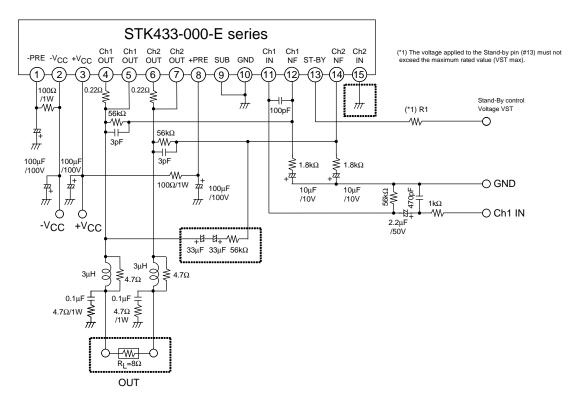
4) DC offset protection block

The DC offset protection circuit is activated when  $\pm 0.5V$  (typ) voltage is applied to either "OUT CH1" or "OUT CH2," and the hybrid IC is shut down (standby mode).

To release the IC from the standby mode and reactivate the power amplifier, it is necessary to set the standby control voltage temporarily low (0V).

Subsequently, when the standby control is returned to high (+5V, for example), the power amplifier will become active again.

The protection level must be set using the  $82k\Omega$  resistor. Furthermore, the time constant must be determined using  $22\mu//22\mu$  capacitors to prevent the amplifier from malfunctioning due to the audio signal.



## STK433-000 Series BTL Application

- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of October, 2009. Specifications and information herein are subject to change without notice.